

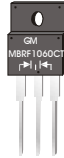
MBRF1020CT THRU MBRF10200CT



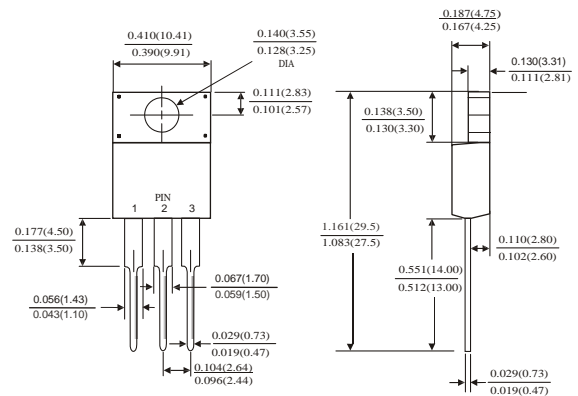
SCHOTTKY BARRIER RECTIFIER
Reverse Voltage - 20 to 200 Volts
Forward Current - 10.0Amperes

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- Dual rectifier construction
- High temperature soldering guaranteed:260 °C/10 seconds, 0.25"(6.35mm)from case
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



ITO-220AB



Dimensions in inches and (millimeters)

MECHANICAL DATA

- Case: JEDEC ITO-220AB molded plastic body
- Terminals: Lead solderable per MIL-STD-750,method 2026
- Polarity: As marked.
- Mounting Position: Any
- Weight: 0.08ounce, 2.24 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

	Symbols	MBRF 1020CT	MBRF 1030CT	MBRF 1040CT	MBRF 1050CT	MBRF 1060CT	MBRF 1080CT	MBRF 10100CT	MBRF 10150CT	MBRF 10200CT	Units	
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	80	100	150	200	Volts	
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	56	70	105	140	Volts	
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	80	100	150	200	Volts	
Maximum average forward rectified current(see Fig.1)	$I_{(AV)}$	5.0									Amps	
		10.0										
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	150									Amps	
Maximum instantaneous forward voltage at 10.0 A(Note 1)	V_F	0.60			0.75		0.85		0.90		0.95	Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	I_R	0.2									mA	
	$T_x = 25\text{ C}$	15			50							
Typical thermal resistance (Note 2)	$R_{\theta JC}$	2.5									C/W	
Operating junction temperature range	T_J	-65 to +150									C	
Storage temperature range	T_{STG}	-65 to +150									C	

Notes: 1.Pulse test: 300 μ s pulse width,1% duty cycle

2.Thermal resistance from junction to case

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RATINGS AND CHARACTERISTIC CURVES

FIG.1-FORWARD CURRENT DERATING CURVE

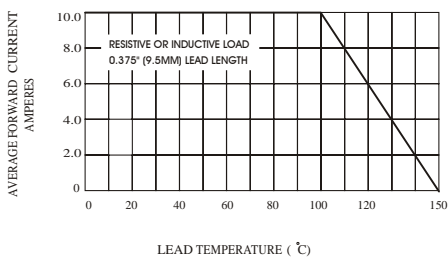


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

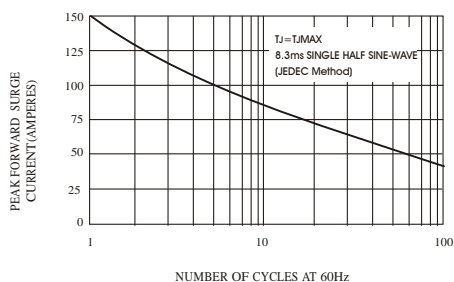


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

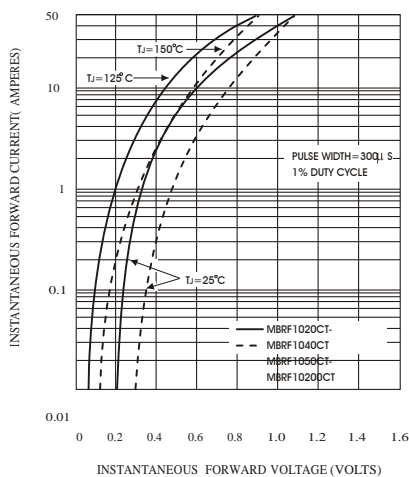


FIG.4-TYPICAL REVERSE CHARACTERISTICS

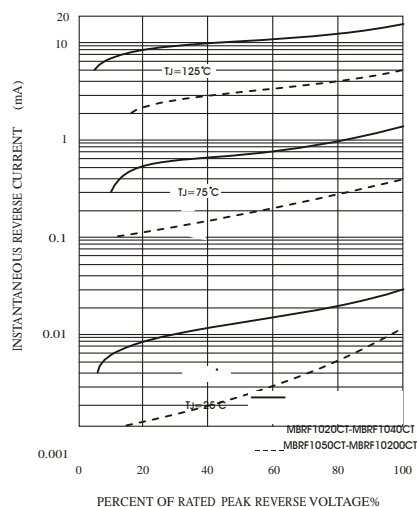


FIG.5-TYPICAL JUNCTION CAPACITANCE

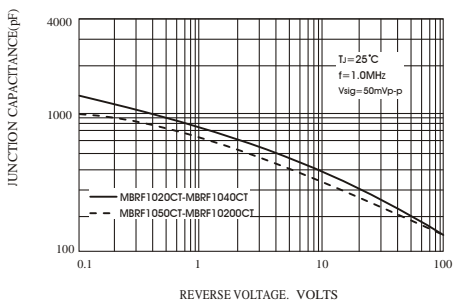


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

